

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	107	("5386138" "5717250" "5998837" "6294426" "6838692")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/27 12:53
L2	108	("5386138" "5717250" "5998837" "6294426" "6838692") or 10/760503	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/27 12:53
L3	34	I2 and (polysilicon near2 plug)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/27 12:58
L4	92	(257/774.ccls. or 257/776.ccls. or 257/653.ccls. or 257/E29.113.ccls. or 257/E29.327.ccls.) and (polysilicon near (trench or via or plug))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/27 12:59
L5	142	(257/774.ccls. or 257/776.ccls. or 257/653.ccls. or 257/E29.113.ccls. or 257/E29.327.ccls.) and (polysilicon near2 (trench or via or plug))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/27 13:00
L18	34	(257/774.ccls. or 257/776.ccls. or 257/653.ccls. or 257/E29.113.ccls. or 257/E29.327.ccls.) and ((polysilicon near2 (trench or via or plug)) same ((impurity or diffusion or source or drain or source/drain) near region))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/27 13:01
L19	16	(257/774.ccls. or 257/776.ccls. or 257/653.ccls. or 257/E29.113.ccls. or 257/E29.327.ccls.) and ((polysilicon near2 (trench or via or plug)) same ((impurity or diffusion or source or drain or source/drain) near region) same (wire or wiring or interconnect or interconnection or electrode))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/27 13:02

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L20	7	(257/774.ccls. or 257/776.ccls. or 257/653.ccls. or 257/E29.113.ccls. or 257/E29.327.ccls.) and ((polysilicon near2 (trench or via or plug)) same ((impurity or diffusion or source or drain or source/drain) near region) same (wire or wiring or interconnect or interconnection or electrode)) and ((impurity or diffusion or dope or doping or doped or dopant) near10 (concentration or content or level))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/27 13:03
L21	8	(257/774.ccls. or 257/776.ccls. or 257/653.ccls. or 257/E29.113.ccls. or 257/E29.327.ccls.) and ((polysilicon near2 (trench or via or plug)) same ((impurity or diffusion or source or drain or source/drain) near region) same (wire or wiring or interconnect or interconnection or electrode)) and ((impurity or diffusion or dope or doping or doped or dopant) near10 (density or concentration or content or level))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/27 13:03